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	,u	THE UNITED STATES PAT	ENT AND TRADEMARK OFFICE
In re A	pplication o Xu et al.	f:	§ Group Art Unit: 2858 § Examiner: Unknown
Serial No. 10/699,352			9 § Atty. Dkt. No. 5589-05001
Filed:	October 31	, 2003	§ I hereby certify that this correspondence is being deposited with the U.S. Postal Service as First Class Mail in an envelope
For:	DETERMI	S AND SYSTEMS FOR NING AN ELECTRICAL Y OF AN INSULATING	addressed to: Commissioner for Patents, P.O. Box 1450 Alexandria, VA 22313, on the date indicated below:  Solvent Date  Solvent Date  Solvent Date  Solvent Date  Pamela Gerik
		INFORMATION DISC	SLOSURE STATEMENT
P.O. B	issioner for lox 1450 ox 1450 adria, VA 22		
Sir/Ma	dam:		
	the addit	•	e references listed on the attached Form PTO-1449 w in paragraph 3. A copy of each reference listed on
1.	This Inform	nation Disclosure Statement is su	bmitted:
	a.	prosecution application und within 3 months of the date an International application before the mailing date of a	of entry of the national stage as set forth in § 1.491 in first Office Action on the merits; or first Office Action after the filing of a request for
	b. 🗆	Office Action or Notice	paragraph 1a and prior to the mailing date of a final of Allowance, and thus: $\Box$ the certification of led, $\underline{\text{or}} \Box$ a fee of \$180.00 is enclosed.
	c. 🗆	_	inal Office Action or a Notice of Allowance and prior e, and thus: the certification of paragraph 2 below is 00 is enclosed.

2.	It is h	It is hereby certified:			
		that each item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the Statement, or			
		that no item of information contained in the Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to the knowledge of the person signing the certification after making reasonable inquiry, was known to any individual designated in § 1.56 (c) more than three months prior to the filing of the Statement.			
3.		Consideration of the following additional information (including any co-pending or abandoned U.S. applications, prior uses and/or sales, etc.) is requested:			
4.	For each non-English language reference listed on the attached Form PTO-1449:				
		reference is made to an English language translation submitted herewith, and/or			
		reference is made to a foreign patent office search report (in the English language) submitted herewith, and/or			
		reference is made to an English language translation of a foreign patent office search report submitted herewith, and/or			
		reference is made to the concise explanation contained in the specification of the present application at page(s), and/or			
		reference is made to the concise explanation set forth below:			
5.		Applicant also offers the following comments for the Examiner's consideration:			
6.		Also enclosed is a copy of a foreign search report citing these references.			
7.		The listed documents were brought to the attention of the Applicant(s) after payment of the issue fee in the captioned case. The documents were cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Information Disclosure Statement. Applicant(s) request this Information Disclosure Statement and attached Form PTO-1449 be placed in the file of the captioned application.			
8.		Applicant(s) requests that the Information Disclosure Statement and attached Form PTO-1449 and references, which are being filed before the grant of the patent and pursuant to 37 C.F.R. § 1.97(i), be placed in the file of the captioned application.			

If any required fees are missing, the Commissioner is authorized to charge said fees to Conley Rose, P.C. Deposit Account No. 03-2769/5589-05001.

Respectfully submitted,

Ann Marie Mewherter

Reg. No. 50,484

Agent for Applicant(s)

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Date: 5-5-04

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Form PTO-1449 (modified)

List of Patents and Publications EMAP For Applicant's Information Disclosure Statement

TTY. DKT. NO. 5589-05001

SERIAL NO. 10/699,352

APPLICANT: Xu et al.

**GROUP: 2858** 

## FILING DATE: October 31, 2003 (Use several sheets if necessary) **U.S. PATENT DOCUMENTS** EXAM. REF. **DOCUMENT NUMBER** DATE NAME CLASS **SUB** FILING DATE IF **APPROPRIATE CLASS INITIALS** DES. **FOREIGN PATENT DOCUMENTS TRANSLATION** CLASS EXAM. REF. **DOCUMENT NUMBER** DATE COUNTRY SUB YES/NO **INITIALS** DES. **CLASS** 1998-12-17 WO Α1 98/57358 OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.) Cosway et al., "Manufacturing Implementation of Corona Oxide Silicon (COS) Systems for Diffusion Furnace Contamination Monitoring," 1997 IEEE/SEMI Advanced Semiconductor Manufacturing Conference, pp. 98-102. Miller, "A New Approach for Measuring Oxide Thickness," Semiconductor International, July 1995, pp. **A3** 147-148. Numerical Recipies in C, The Art of Scientific Computing, 2nd Ed., © Cambridge University Press A4 1988, 1992, p. 683. Weinberg, "Tunneling of Electrons from Si into Thermally Grown SiO<sub>2</sub>," Solid-State Electronics, **A5** 1977, Vol. 20, pp. 11-18. Verkuil, "Rapid Contactless Method for Measuring Fixed Oxide Charge Associated with Silicon A6 Processing," IBM Technical Disclosure Bulletin, Vol. 24, No. 6, 1981, pp. 3048-3053. "Contactless Photovoltage vs. Bias Method for Determining Flat-Band Voltage," IBM Technical **A7** Disclosure Bulletin, Vol. 32, Vol. 9A, 1990, pp. 14-17. "Contactless Electrical Equivalent Oxide Thickness Measurement." IBM Technical Disclosure **A8** Bulletin, Vol. 29, No. 10, 1987, pp. 4622-4623.

## **EXAMINER:**

## DATE CONSIDERED:

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the patent owner.